



NGFP15T65M3DFP

650 V, 15 A trench field-stop IGBT with full rated silicon diode

Rev. 1 — 6 June 2025

Product data sheet

1. General description

NGFP15T65M3DFP is a robust Insulated-Gate Bipolar Transistor (IGBT) featuring third-generation technology. It combines carrier stored trench-gate and field-stop (FS) structures. NGFP15T65M3DFP is rated to 175 °C with optimized IGBT turn-off losses, and has a short circuit withstand time of 5 µs. This hard-switching 650 V, 15 A IGBT is optimized for high-voltage, high-frequency industrial power inverter applications and servo motor drive applications.

2. Features

- Device current is rated at 15 A
- Low conduction and switching losses
- Stable and tight parameters for easy parallel operation
- Maximum junction temperature 175 °C
- Fully rated and fast reverse recovery diode
- 5 µs short circuit withstand time

3. Applications

- Motor drives for industrial and consumer appliances
 - Servo motors operating between 5-20 kW (up to 20 kHz) for robotics, elevators, operating grippers, in-line manufacturing, etc.
- Power converter applications, such as uninterruptible power supply (UPS)
- Induction heating
- Welding

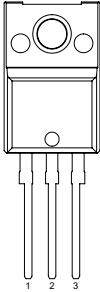
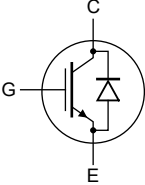
4. Quick reference data

Table 1. Quick reference data

Symbol	Parameter	Conditions	Min	Max	Unit
V_{CES}	collector-emitter voltage	$T_{vj} = 25\text{ °C}$	-	650	V
T_{vj}	operating junction temperature		-40	175	°C
t_{sc}	short circuit withstand time	$V_{GE} = 15\text{ V}; V_{CC} = 400\text{ V}; T_{vj} \leq 150\text{ °C}$	-	5.0	µs

5. Pinning information

Table 2. Pinning information

Pin	Symbol	Description	Simplified outline	Graphic symbol
1	G	gate		 aaa-036518
2	C	collector		
3	E	emitter		

6. Ordering information

Table 3. Ordering information

Type number	Package		
	Name	Description	Version
NGFP15T65M3DFP	TO220-3 FP	Plastic single-ended through-hole package; 1 mounting hole; 3-lead TO220-3 FP	SOT186B-1

7. Limiting values

Table 4. Limiting values

Symbol	Parameter	Conditions	Min	Max	Unit
IGBT					
V _{CES}	collector-emitter voltage	T _{vj} = 25 °C	-	650	V
I _C	collector current	[1] T _c = 25 °C	-	16	A
		T _c = 100 °C	-	10.2	A
I _{CRM}	repetitive peak collector current	[2]	-	45	A
t _{sc}	short circuit withstand time	[3] V _{GE} = 15 V; V _{CC} = 400 V; T _{vj} ≤150 °C	-	5	µs
V _{GE}	gate-emitter voltage		-20	20	V
P _{tot}	total power dissipation	T _c = 25 °C	-	38	W
		T _c = 100 °C	-	19	W
T _{vj}	operating junction temperature		-40	175	°C
T _{stg}	storage temperature		-55	150	°C
T _{solder}	soldering temperature		-	260	°C
Diode					
I _F	diode forward current	[1] T _c = 25 °C	-	17.5	A
		T _c = 100 °C	-	10.3	A
I _{FRM}	repetitive peak forward current	[2]	-	45	A

[1] Value is limited by internal bonding wire and T_{vj(max)}.
 [2] Time duration is limited by T_{vj(max)}.
 [3] Short circuit cycles ≤ 1000, time between tests ≥ 1 s.

8. Thermal characteristics

Table 5. Thermal characteristics

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
M	mounting torque, M3 screw		-	0.5	-	Nm
R _{th(j-c)}	thermal resistance from junction to case	IGBT	-	-	3.90	K/W
		diode	-	-	4.88	K/W
R _{th(j-a)}	thermal resistance from junction to ambient	in free air	-	-	65	K/W

9. Electrical characteristics

Table 6. Characteristics

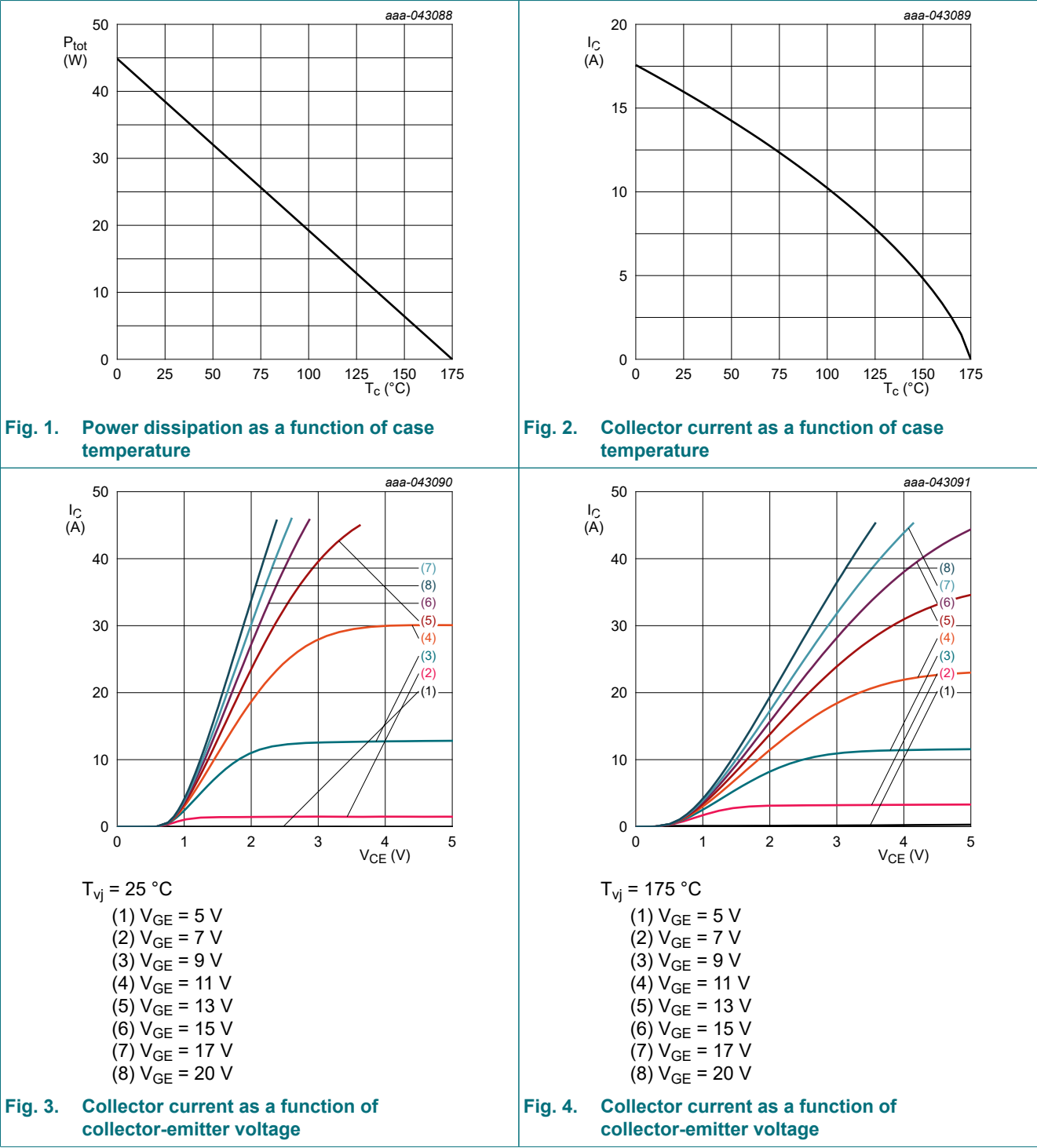
All values at T_{vj} = 25 °C, unless otherwise specified.

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
Static characteristics						
V _{(BR)CES}	collector-emitter breakdown voltage	V _{GE} = 0 V; I _C = 0.2 mA	650	-	-	V
V _{CEsat}	collector-emitter saturation voltage	V _{GE} = 15 V; I _C = 15 A; T _{vj} = 25 °C	-	1.51	1.8	V
		V _{GE} = 15 V; I _C = 15 A; T _{vj} = 175 °C	-	1.95	-	V
V _F	diode forward voltage	V _{GE} = 0 V; I _F = 15 A; T _{vj} = 25 °C	-	1.58	2.0	V
		V _{GE} = 0 V; I _F = 15 A; T _{vj} = 175 °C	-	1.32	-	V
V _{GE(th)}	gate-emitter threshold voltage	I _C = 0.15 mA; V _{CE} = V _{GE} ; T _{vj} = 25 °C	4.3	5.0	5.7	V
I _{CES}	zero gate voltage collector current	V _{CE} = 650 V; V _{GE} = 0 V; T _{vj} = 25 °C	-	3	-	nA
		V _{CE} = 650 V; V _{GE} = 0 V; T _{vj} = 175 °C	-	0.2	-	mA
I _{GES}	gate-emitter leakage current	V _{CE} = 0 V; V _{GE} = 20 V	-	-	100	nA
g _{fs}	transconductance	V _{CE} = 20 V; I _C = 15 A; T _{vj} = 25 °C	-	7.1	-	S
r _g	internal gate resistor		-	2.0	-	Ω
Dynamic characteristics						
C _{ies}	input capacitance	V _{CE} = 25 V; V _{GE} = 0 V; f = 1 MHz	-	1150	-	pF
C _{oes}	output capacitance		-	49	-	pF
C _{res}	reverse transfer capacitance		-	11	-	pF
Q _G	gate charge	V _{CC} = 520 V; I _C = 15 A; V _{GE} = 15 V	-	46	-	nC
L _{sCE}	internal stray inductance	measured 5 mm from case	-	6.6	-	nH
I _{C(sc)}	short circuit collector current	V _{GE} = 15 V; V _{CC} = 400 V; t _{sc} ≤ 5 μs; T _{vj} ≤ 150 °C	-	75	-	A

Symbol	Parameter	Conditions	Min	Typ	Max	Unit	
IGBT switching characteristics, inductive load							
t _{d(on)}	turn-on delay time	V _{GE} = 15/0 V; V _{CC} = 400 V; I _C = 15 A; R _{G(on)} = 10 Ω; R _{G(off)} = 10 Ω; see Fig. 27 and Fig. 28	T _{vj} = 25 °C	-	12	-	ns
			T _{vj} = 175 °C	-	11	-	ns
t _r	rise time		T _{vj} = 25 °C	-	7	-	ns
			T _{vj} = 175 °C	-	9	-	ns
t _{d(off)}	turn-off delay time		T _{vj} = 25 °C	-	86	-	ns
			T _{vj} = 175 °C	-	114	-	ns
t _f	fall time		T _{vj} = 25 °C	-	33	-	ns
			T _{vj} = 175 °C	-	66	-	ns
E _{on}	turn-on switching energy loss		T _{vj} = 25 °C	-	0.32	-	mJ
			T _{vj} = 175 °C	-	0.72	-	mJ
E _{off}	turn-off switching energy loss		T _{vj} = 25 °C	-	0.17	-	mJ
			T _{vj} = 175 °C	-	0.29	-	mJ
E _{ts}	total switching energy loss		T _{vj} = 25 °C	-	0.49	-	mJ
			T _{vj} = 175 °C	-	1.01	-	mJ
Diode switching characteristics, inductive load							
t _{rr}	reverse recovery time	V _R = 400 V; I _F = 15 A; di _F /dt = 500 A/μs; see Fig. 26	T _{vj} = 25 °C	-	84	-	ns
			T _{vj} = 175 °C	-	168	-	ns
Q _{rr}	reverse recovery charge		T _{vj} = 25 °C	-	442	-	nC
			T _{vj} = 175 °C	-	1583	-	nC
I _{rrm}	peak reverse recovery current		T _{vj} = 25 °C	-	14	-	A
			T _{vj} = 175 °C	-	23	-	A
E _{rec}	reverse recovery energy loss		T _{vj} = 25 °C	-	0.05	-	mJ
			T _{vj} = 175 °C	-	0.27	-	mJ
di _{rrf} /dt	fall rate of reverse recovery current		T _{vj} = 25 °C	-	286	-	A/μs
			T _{vj} = 175 °C	-	239	-	A/μs

9.1. Characteristic diagrams

Table 7. Waveforms and output characteristics



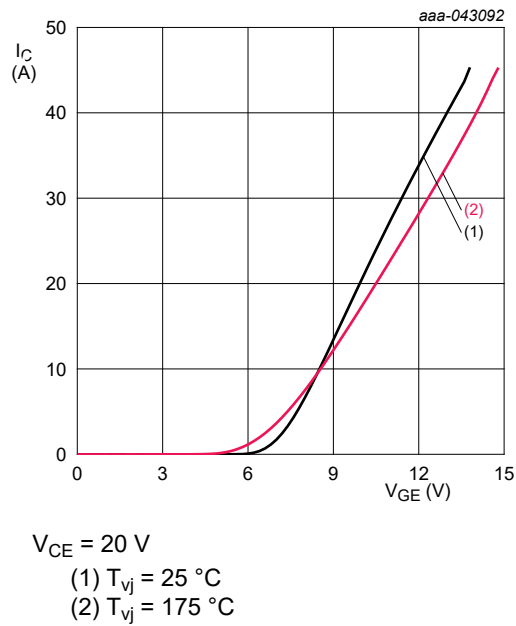


Fig. 5. Collector current as a function of gate-emitter voltage

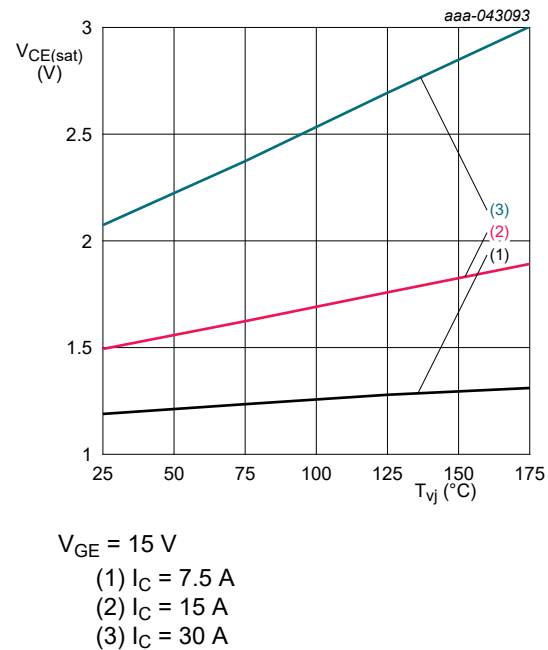


Fig. 6. Collector-emitter saturation voltage as a function of junction temperature

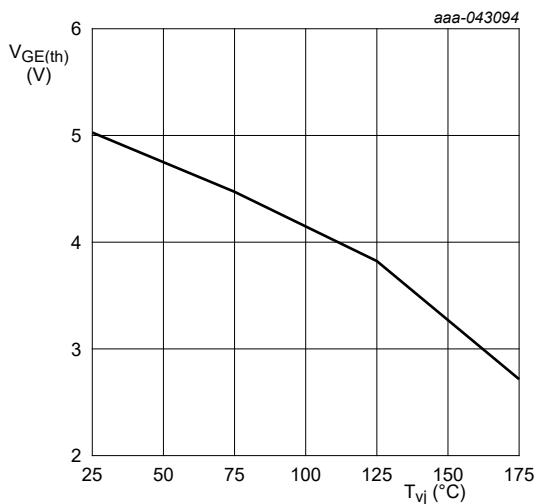


Fig. 7. Gate-emitter threshold voltage as a function of junction temperature

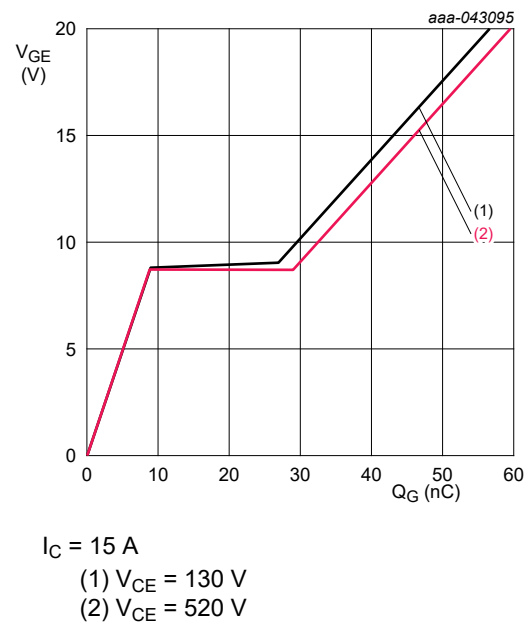
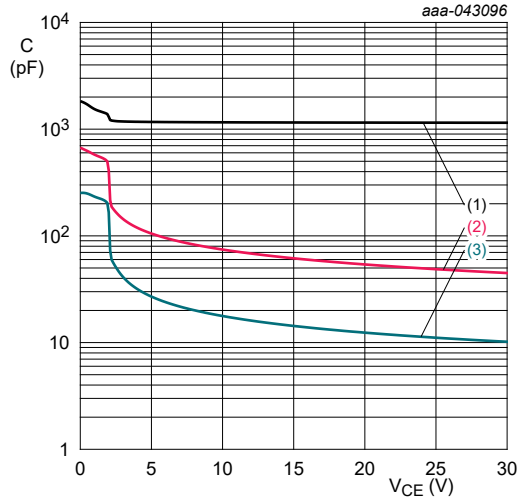


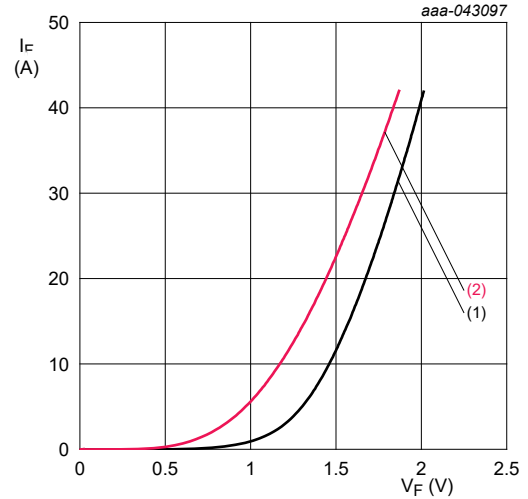
Fig. 8. Gate-emitter voltage as a function of gate charge



$V_{GE} = 0 \text{ V}$; $f = 1 \text{ MHz}$

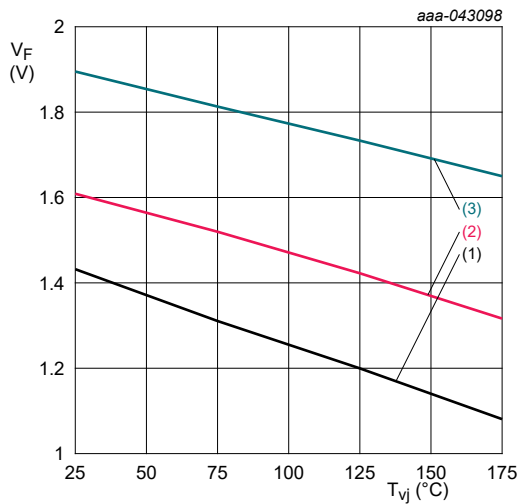
- (1) C_{ies}
- (2) C_{oes}
- (3) C_{res}

Fig. 9. Typical capacitance as a function of collector-emitter voltage



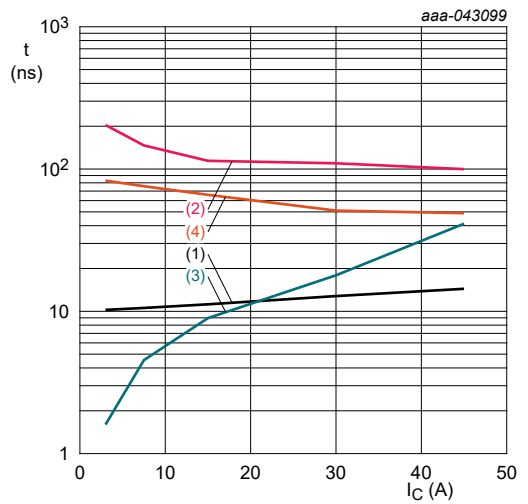
- (1) $T_{vj} = 25 \text{ °C}$
- (2) $T_{vj} = 175 \text{ °C}$

Fig. 10. Typical diode forward current as a function of forward voltage



- (1) $I_F = 7.5 \text{ A}$
- (2) $I_F = 15 \text{ A}$
- (3) $I_F = 30 \text{ A}$

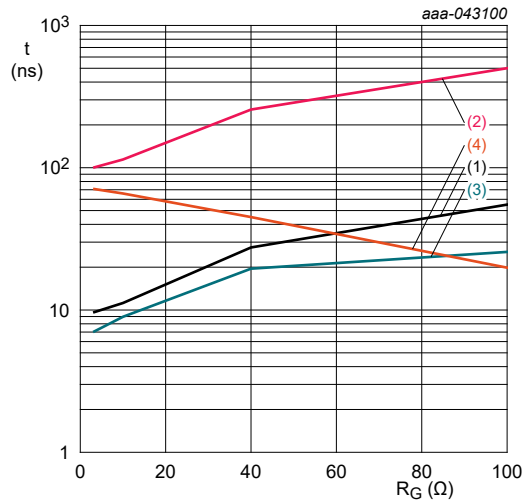
Fig. 11. Typical diode forward voltage as a function of junction temperature



$V_{GE} = 15 \text{ V to } 0 \text{ V}$; $V_{CC} = 400 \text{ V}$; $R_{G(on)} = 10 \text{ } \Omega$;
 $R_{G(off)} = 10 \text{ } \Omega$; $T_{vj} = 175 \text{ °C}$

- (1) $t_{d(on)}$
- (2) $t_{d(off)}$
- (3) t_r
- (4) t_f

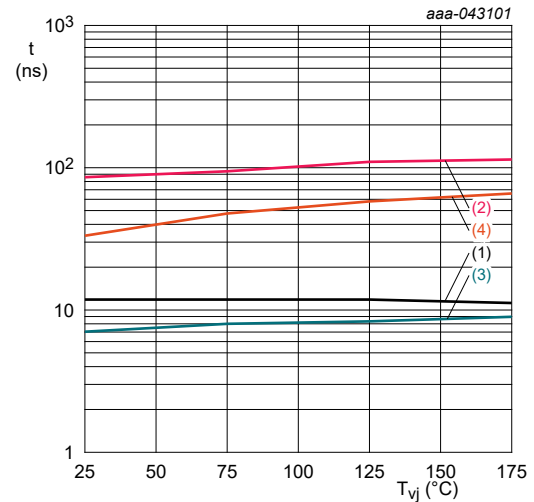
Fig. 12. Typical switching times as a function of collector current



$V_{GE} = 15 \text{ V to } 0 \text{ V}; V_{CC} = 400 \text{ V}; I_C = 15 \text{ A};$
 $T_{vj} = 175 \text{ }^\circ\text{C}$

- (1) $t_{d(on)}$
- (2) $t_{d(off)}$
- (3) t_r
- (4) t_f

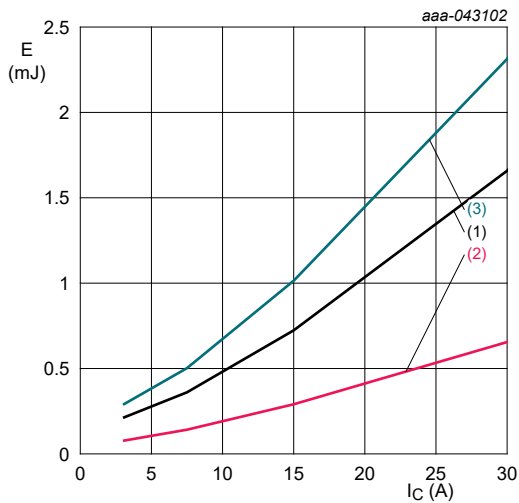
Fig. 13. Typical switching times as a function of gate resistance



$V_{GE} = 15 \text{ V to } 0 \text{ V}; V_{CC} = 400 \text{ V}; I_C = 15 \text{ A};$
 $R_{G(on)} = 10 \text{ } \Omega; R_{G(off)} = 10 \text{ } \Omega$

- (1) $t_{d(on)}$
- (2) $t_{d(off)}$
- (3) t_r
- (4) t_f

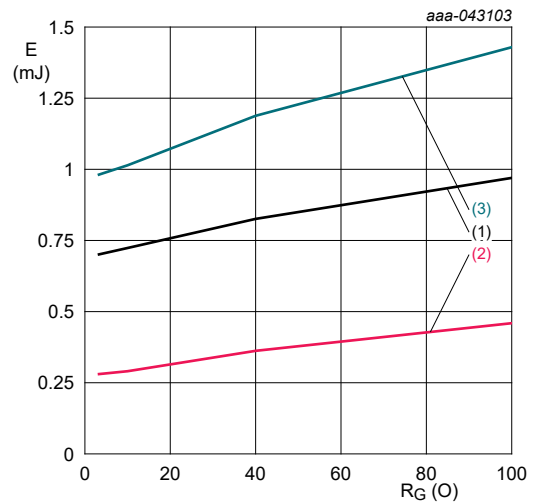
Fig. 14. Typical switching times as a function of junction temperature



$V_{GE} = 15 \text{ V to } 0 \text{ V}; V_{CC} = 400 \text{ V}; R_{G(on)} = 10 \text{ } \Omega;$
 $R_{G(off)} = 10 \text{ } \Omega; T_{vj} = 175 \text{ }^\circ\text{C}$

- (1) E_{on}
- (2) E_{off}
- (3) E_{ts}

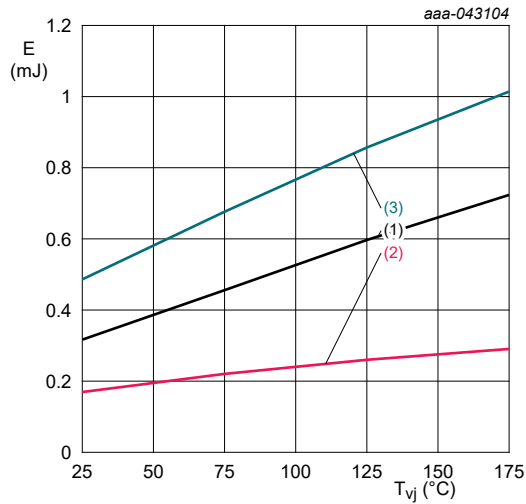
Fig. 15. Typical switching energy losses as a function of collector current



$V_{GE} = 15 \text{ V to } 0 \text{ V}; V_{CC} = 400 \text{ V}; I_C = 15 \text{ A};$
 $T_{vj} = 175 \text{ }^\circ\text{C}$

- (1) E_{on}
- (2) E_{off}
- (3) E_{ts}

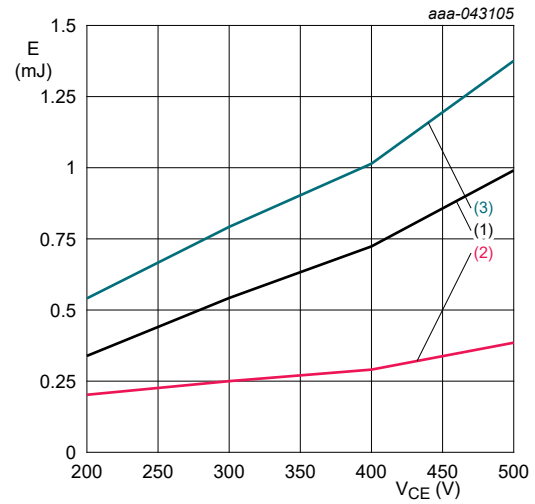
Fig. 16. Typical switching energy losses as a function of gate resistance



$V_{GE} = 15 \text{ V to } 0 \text{ V}$; $V_{CC} = 400 \text{ V}$; $I_C = 15 \text{ A}$;
 $R_{G(on)} = 10 \Omega$; $R_{G(off)} = 10 \Omega$

- (1) E_{on}
- (2) E_{off}
- (3) E_{ts}

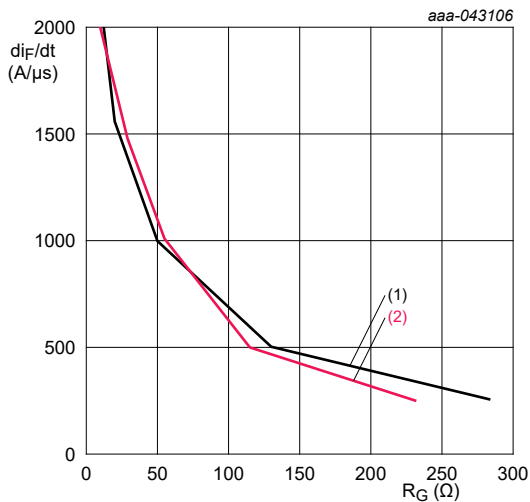
Fig. 17. Typical switching energy losses as a function of junction temperature



$V_{GE} = 15 \text{ V to } 0 \text{ V}$; $I_C = 15 \text{ A}$; $R_{G(on)} = 10 \Omega$;
 $R_{G(off)} = 10 \Omega$; $T_{vj} = 175 \text{ °C}$

- (1) E_{on}
- (2) E_{off}
- (3) E_{ts}

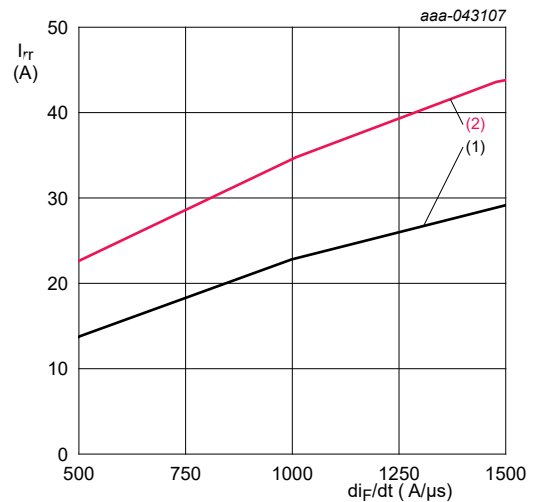
Fig. 18. Typical switching energy losses as a function of collector-emitter voltage



$V_R = 400 \text{ V}$; $I_F = 15 \text{ A}$

- (1) $T_{vj} = 25 \text{ °C}$
- (2) $T_{vj} = 175 \text{ °C}$

Fig. 19. Typical rate of change of forward current as a function of gate resistance



$V_R = 400 \text{ V}$; $I_F = 15 \text{ A}$

- (1) $T_{vj} = 25 \text{ °C}$
- (2) $T_{vj} = 175 \text{ °C}$

Fig. 20. Typical reverse recovery current as a function of rate of change of forward current

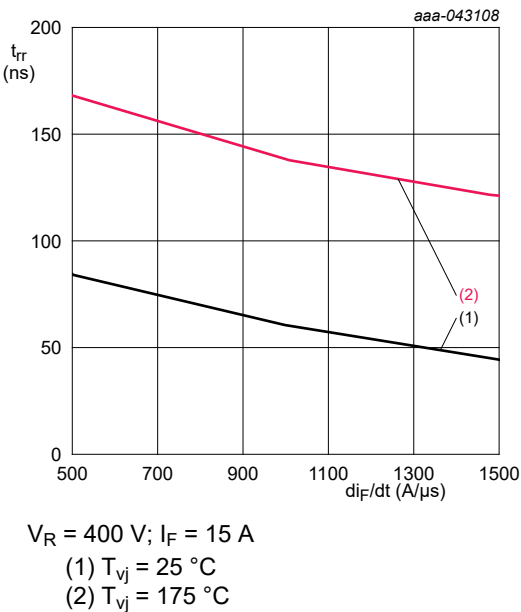


Fig. 21. Typical reverse recovery time as a function of rate of change of forward current

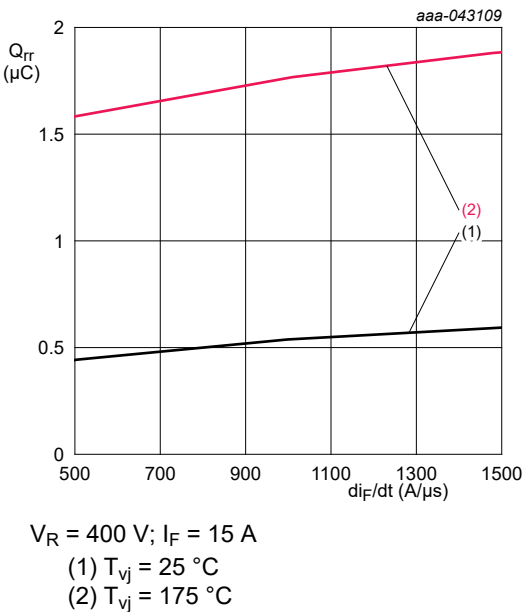


Fig. 22. Typical reverse recovery charge as a function of rate of change of forward current

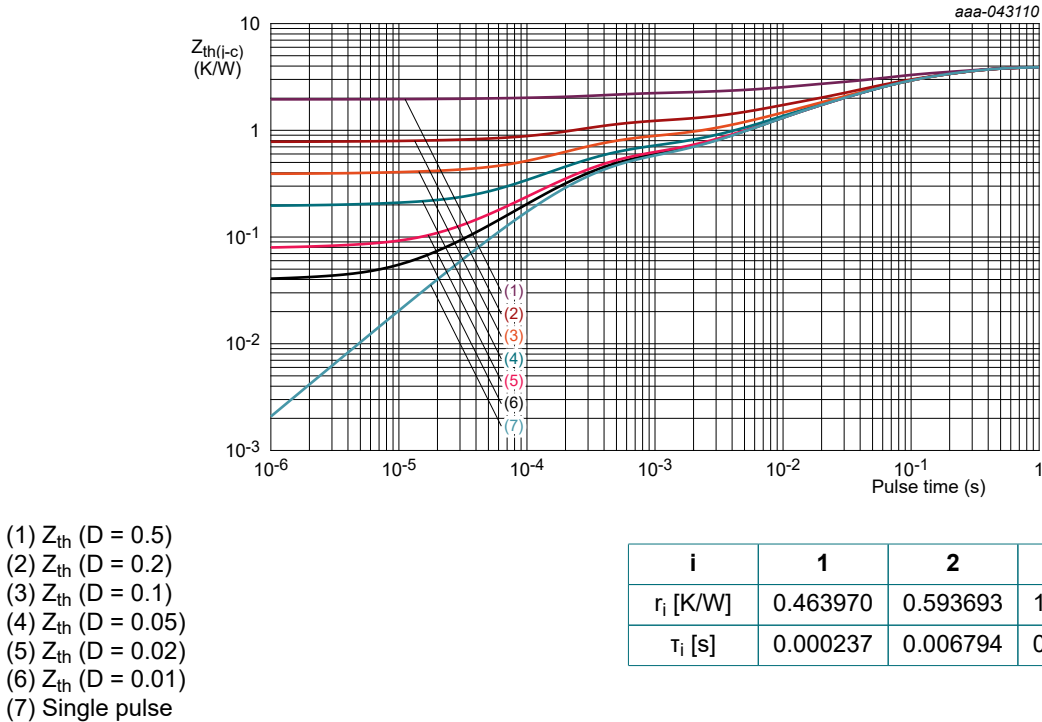
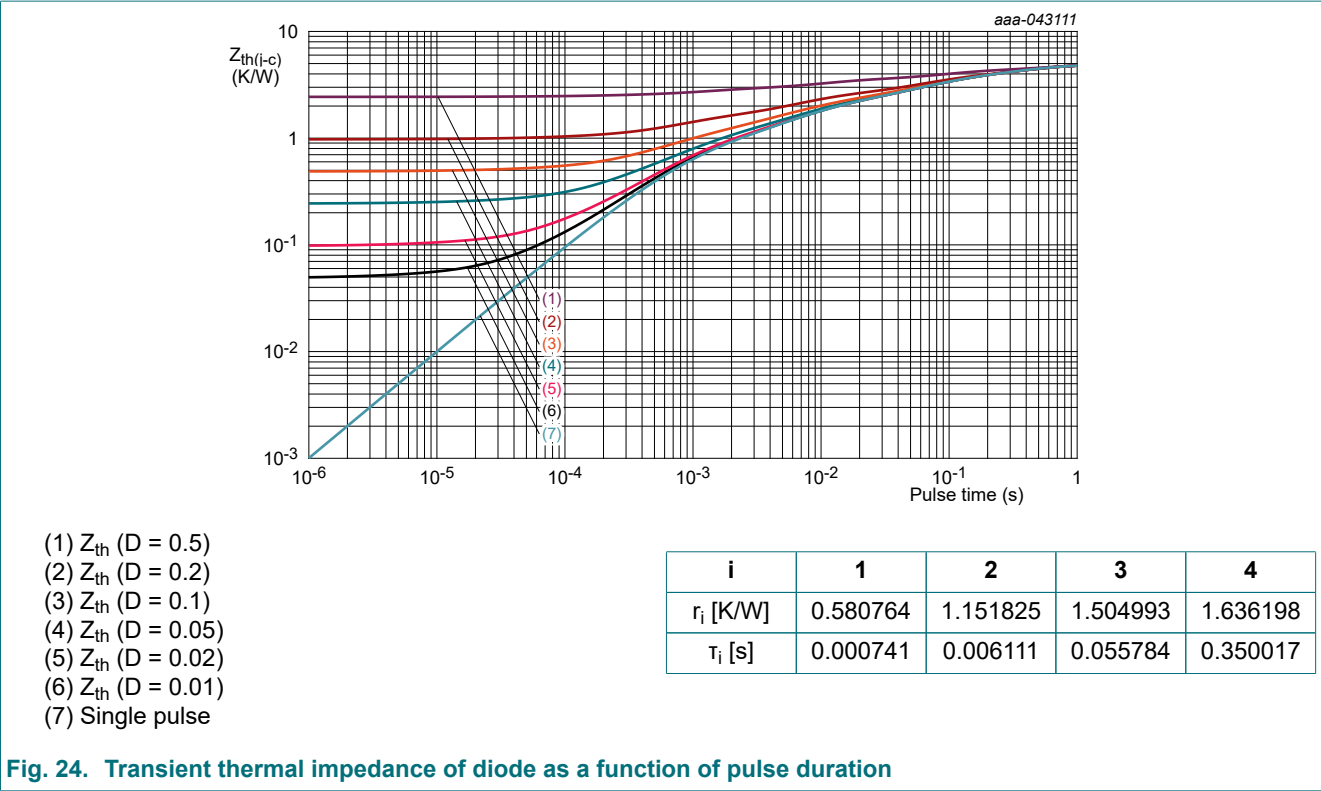
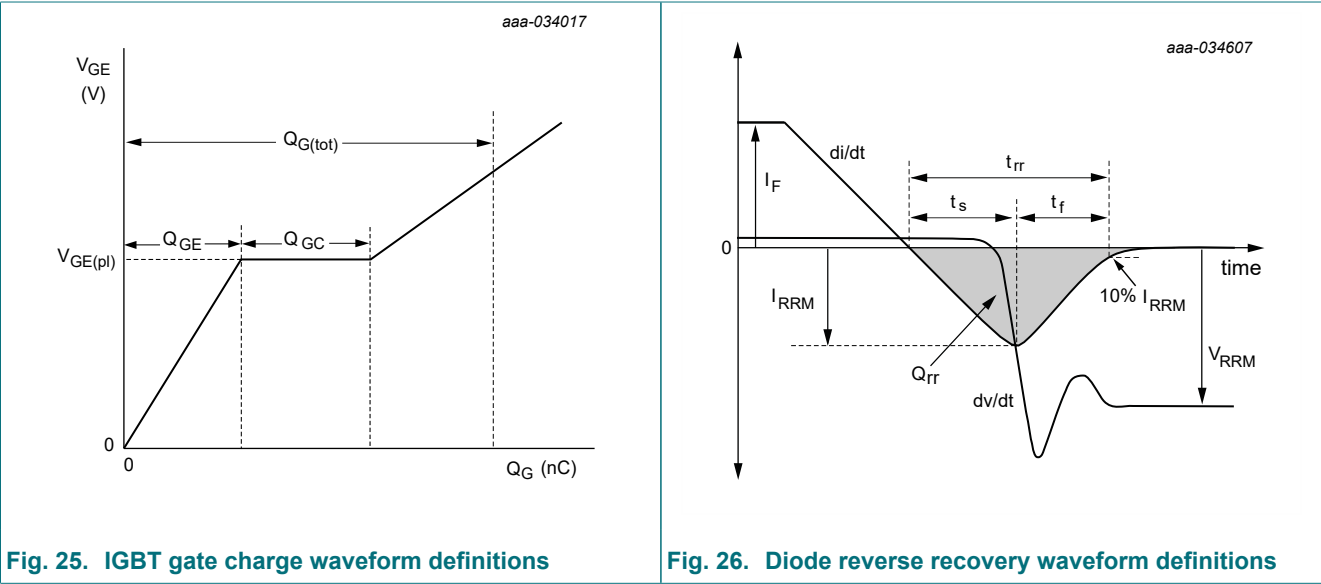
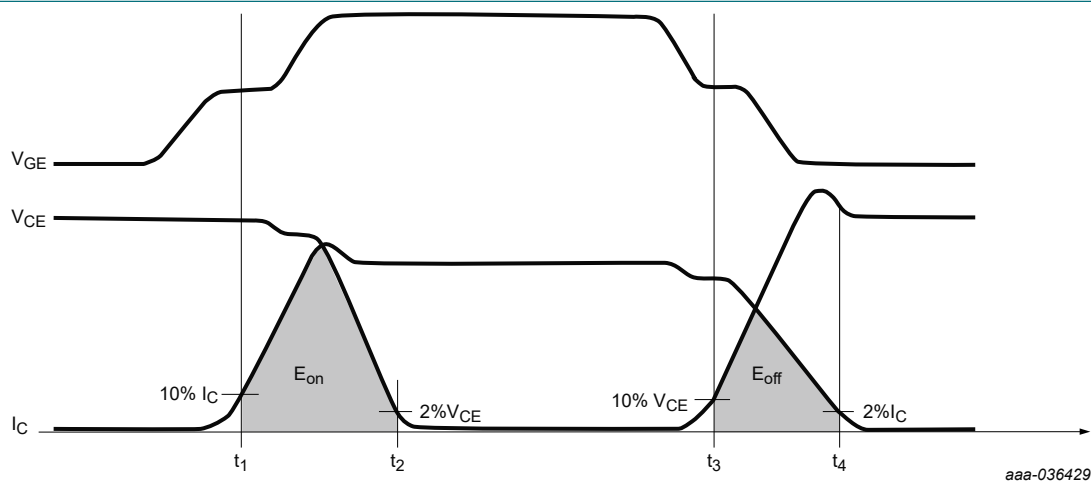
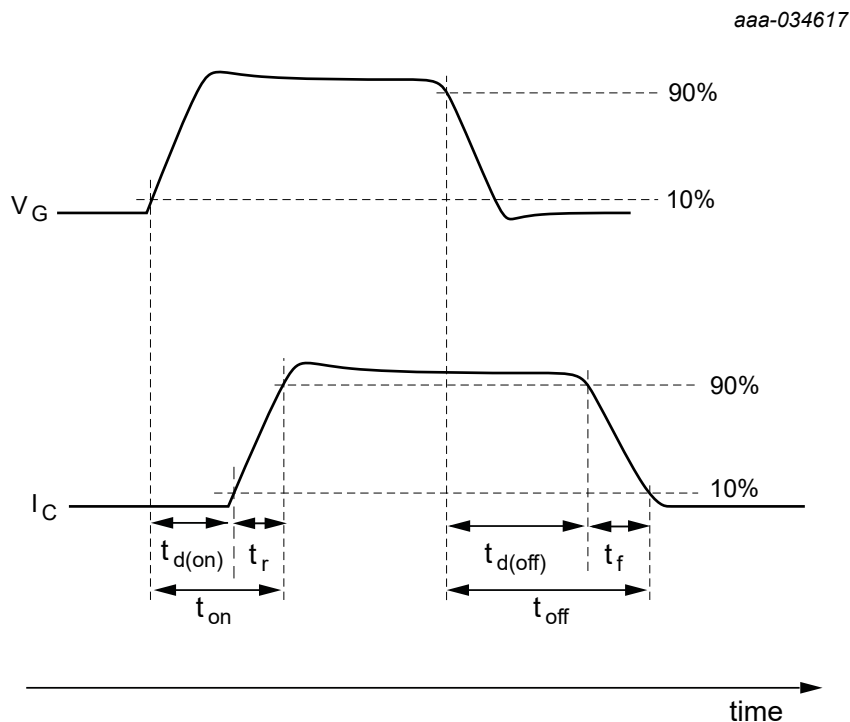


Fig. 23. Transient thermal impedance of IGBT as a function of pulse duration



9.2. Waveform definitions





10. Package outline

plastic, single-ended package; 3 leads; 2.55 mm pitch;
16.15mm x 10.2 mm x 4.5 mm body

SOT186B-1

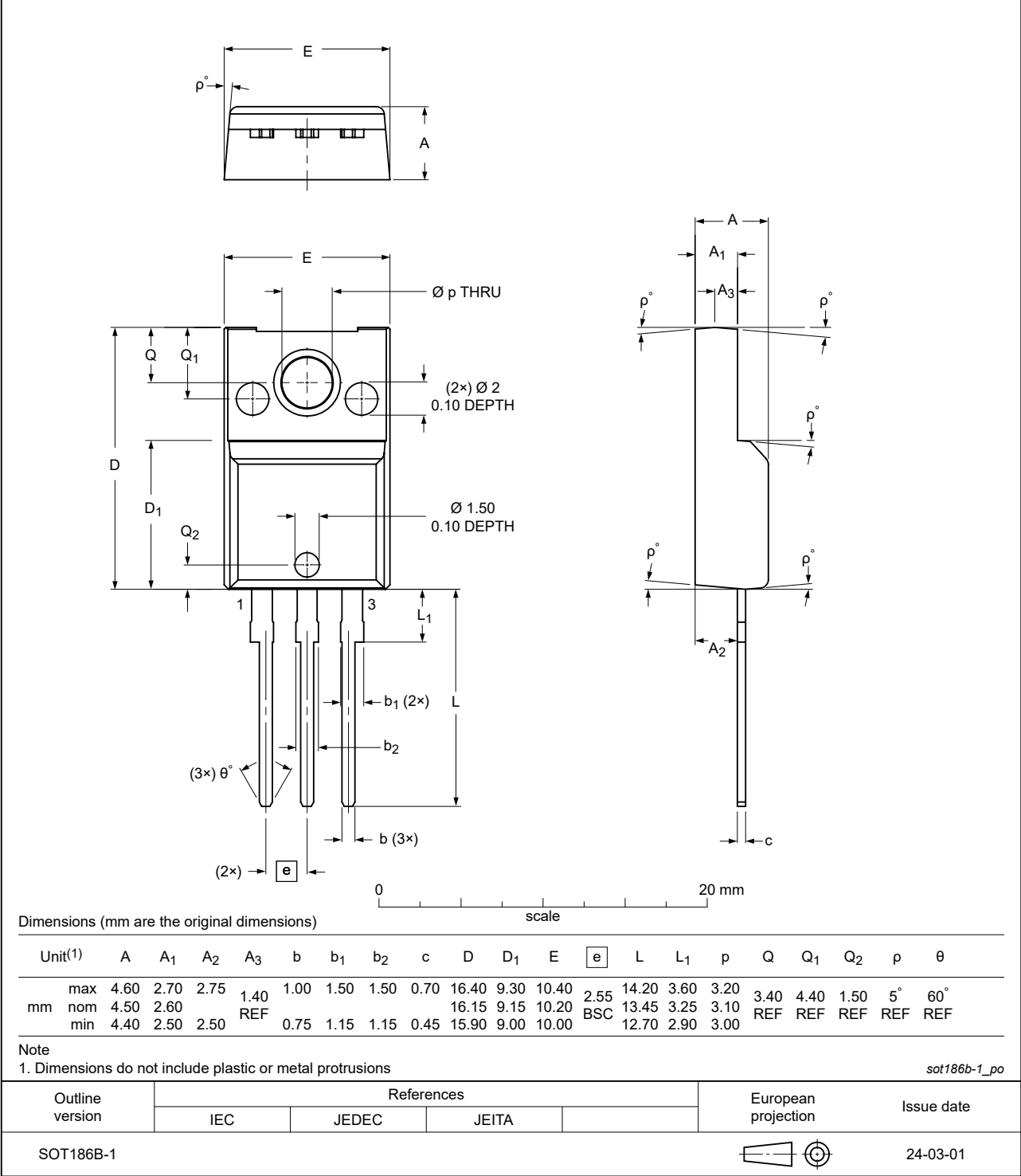


Fig. 29. Package outline TO220-3 FP (SOT186B-1)

11. Revision history

Table 8. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes
NGFP15T65M3DFP v. 1	June 6, 2025	Product data sheet	-	-

12. Legal information

Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

- [1] Please consult the most recently issued document before initiating or completing a design.
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